

PATENT**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Serial No.: 10/797,876
Applicant: Dip et al.
Art Unit: 2811
Title: **SILICON GERMANIUM SURFACE LAYER FOR HIGH-K
DIELECTRIC INTEGRATION**
Attorney Docket: TPS-007
Confirmation No.: 5070

August 4, 2008

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

AMENDMENT - AFTER FINAL REJECTION

This paper is responsive to the Office Action mailed June 3, 2008, made final per MPEP § 706.07(a). The present response includes the following:

Amendments to the Specification: None
Amendments to the Claims: Pages 2-5
Amendments to the Abstract: None
Amendments to the Drawings: None
Remarks: Pages 6-11
Attachments: None